

## Lithography and Laser Processing

## Multifunction Projection Patterning System for Optoelectronics, Microsystems and Biophotonics

The Anvik NexStep™ 1020 SXE microlithography system is a revolutionary advance in *multifunction* laser processing systems. It is an ideal low-cost mini-stepper that offers the unique combination of high-resolution *projection* lithography in photoresists, photoablation in polymers, and high-fluence materials processing of semiconductors and other materials, making it the ideal patterning tool for both pilot production and exploration of new frontiers in micro-optics, optoelectronics, MEMS, microfluidics, and biophotonics in a multi-user, multidisciplinary environment.

### High-Resolution Projection Imaging

- Diffraction-limited projection system provides optical resolution of 2  $\mu\text{m}$  over entire field
- High resolution produces channels, holes, etc. with excellent edge definition and wall profiles
- Projection imaging eliminates limitations of contact / proximity printing and direct writing

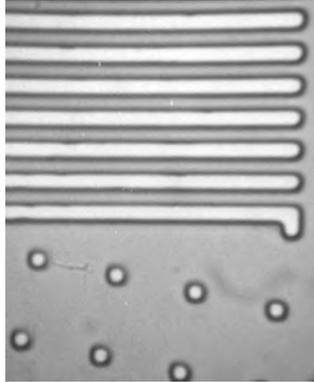
### Versatile Substrate Handling

- Designed for processing substrates of different sizes (up to 150 x 150 mm) and shapes
- Capable of patterning on substrates of a wide range of thicknesses — from 0.05 to 5.0 mm
- Able to handle both rigid (Si wafers, glass plates, etc.) and flexible (e.g., polymer sheets) materials

### Multifunction Capability

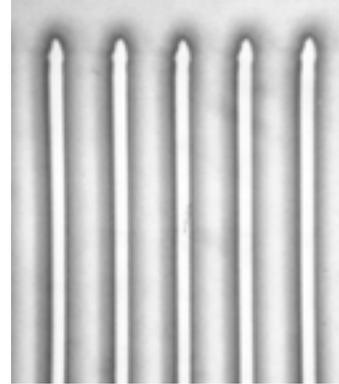
- High-resolution projection patterning of photoresists, polymers and biosurfaces
- Fabrication of MEMS, integrated optics and microfluidics in rigid and flexible materials
- Processing of plastics, e.g., polyvinyls, acrylics, polycarbonates and polyesters
- Laser crystallization of amorphous semiconductors and optoelectronic films for large-area displays and integrated sensors





Left: 2  $\mu\text{m}$  lines, spaces and holes patterned with a 248 nm Anvik system in a deep UV photoresist.

Right: Channels of 5.6  $\mu\text{m}$  width ablated in 8.3  $\mu\text{m}$  thick polyimide using a 308 nm Anvik system.



**Versatility  
and  
Upgradability**

- **Ideal for process development and materials investigations for diverse applications**
- **Upgradable to higher resolutions (submicron) and larger substrate sizes (> 1000 cm<sup>2</sup>)**
- **Readily optimized for dedicated use with any specific process and/or materials set**

**Technology  
Transfer  
Vehicle**

- **System is ideal 'pilot tool' for technology transfer to high-volume manufacturing:**
  - **Projection system and excimer laser source deliver high resolution, yield and throughput**
  - **Upgrade to seamless scanning system enables rapid transition to large-format processing**

<b>NexStep 1020 SXE Specifications</b>	
Imaging Technique	Projection step-&-repeat
Resolution	2 $\mu\text{m}$
Projection System	5:1 reduction refractive lens
Numerical Aperture	0.21 ( $f/2.4$ )
Depth of Focus	14 $\mu\text{m}$
Lens Image Field Size	4 mm diameter (at substrate)
Substrate Size	Up to 150 x 150 mm
Substrate Thickness	0.05 - 5.0 mm
Illumination Source	XeCl excimer laser (KrF or XeF optional)
Exposure Wavelength	308 nm (248 or 351 nm optional)
Fluence at Substrate	Up to 1 J/cm <sup>2</sup>
Substrate Handling	Manual
Alignment System	Manual (automatic optional)

